

# 0.8A, 200V - 1000V Standard Bridge Rectifier

#### **FEATURES**

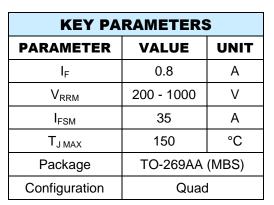
- AEC-Q101 qualified available
- Ideal for automated placement
- Reliable low cost construction utilizing molded plastic technique
- High surge current capability
- UL Recognized File # E-326854
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

| $\Delta D$ | DI           | ICA | TI | 0 | NS.  |
|------------|--------------|-----|----|---|------|
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- Switching mode power supply (SMPS)
- Adapters
- Lighting application

#### **MECHANICAL DATA**

- Case: TO-269AA (MBS)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.120g (approximately)



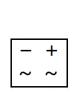


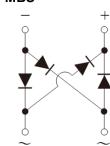












| ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)            |                       |                     |              |      |      |      |                  |      |
|--|-----------------------|---------------------|--------------|------|------|------|------------------|------|
| PARAMETER  |                       | SYMBOL              | MBS2         | MBS4 | MBS6 | MBS8 | MBS10            | UNIT |
| Marking code on the device   |                       |                     | MBS2         | MBS4 | MBS6 | MBS8 | MBS10            |      |
| Repetitive peak reverse voltage  |                       | $V_{RRM}$           | 200          | 400  | 600  | 800  | 1000             | V    |
| Reverse voltage, total rms value   |                       | V <sub>R(RMS)</sub> | 140          | 280  | 420  | 560  | 700              | V    |
| Forward current  | On glass-epoxy        | - I <sub>F</sub>    | 0.5          |      |      |      | Α                |      |
|  | On aluminum substrate |                     | 0.8          |      |      |      | Α                |      |
| Surge peak forward current, 8.3ms single half sine-wave superimposed on rated load |                       | I <sub>FSM</sub>    | 35           |      |      |      |                  | А    |
| Rating for fusing (t<8.3ms)  |                       | l <sup>2</sup> t    | 5.08         |      |      |      | A <sup>2</sup> s |      |
| Junction temperature   |                       | TJ                  | - 55 to +150 |      |      |      | °C               |      |
| Storage temperature  |                       | T <sub>STG</sub>    | - 55 to +150 |      |      |      | °C               |      |

1



| THERMAL PERFORMANCE                                   |                  |     |      |  |
|---|------------------|-----|------|--|
| PARAMETER   | SYMBOL           | TYP | UNIT |  |
| Junction-to-lead thermal resistance <sup>(1)</sup>    | R <sub>OJL</sub> | 20  | °C/W |  |
| Junction-to-ambient thermal resistance <sup>(2)</sup> | R <sub>ÐJA</sub> | 70  | °C/W |  |
| Junction-to-ambient thermal resistance <sup>(1)</sup> | R <sub>OJA</sub> | 85  | °C/W |  |

## Notes:

- 1. On glass epoxy P.C.B. mounted on 0.05" x 0.05" (1.3mm x 1.3mm) pads
- 2. On aluminum substrate P.C.B. with an area of 0.8" x 0.8" (20mm x 20mm) mounted on 0.05" x 0.05" (1.3mm x 1.3mm) solder pads

| ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted) |   |                |     |     |      |
|--|---|----------------|-----|-----|------|
| PARAMETER  | CONDITIONS                                  | SYMBOL         | TYP | MAX | UNIT |
| Forward voltage per diode <sup>(1)</sup>                                 | I <sub>F</sub> = 0.4A,T <sub>J</sub> = 25°C | V <sub>F</sub> | -   | 1   | V    |
| Reverse current @ rated V <sub>R</sub> per diode <sup>(2)</sup>          | T <sub>J</sub> = 25°C                       |                | -   | 5   | μA   |
| Reverse current & rated v <sub>R</sub> per diode                         | T <sub>J</sub> = 125°C                      | I <sub>R</sub> | -   | 100 | μA   |
| Junction capacitance per diode   | $1MHz, V_R = 4.0V$                          | CJ             | 13  | -   | pF   |

## Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

| ORDERING INFORMATION            |                |                     |  |  |  |
|---------------------------------|----------------|---------------------|--|--|--|
| ORDERING CODE <sup>(1)(2)</sup> | PACKAGE        | PACKING             |  |  |  |
| MBSx                            | TO-269AA (MBS) | 3,000 / Tape & Reel |  |  |  |
| MBSxH                           | TO-269AA (MBS) | 3,000 / Tape & Reel |  |  |  |

#### Notes:

- 1. "x" defines voltage from 200V(MBS2) to 1000V(MBS10)
- 2. "H" means AEC-Q101 qualified



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

**Fig.1 Forward Current Derating Curve** 

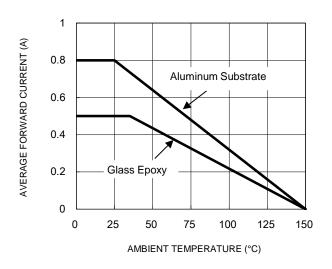


Fig.3 Typical Reverse Characteristics

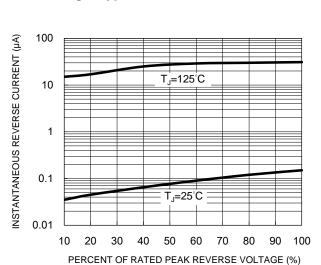


Fig.2 Typical Junction Capacitance

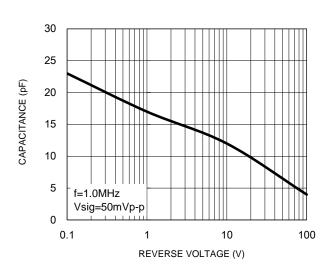


Fig.4 Typical Forward Characteristics

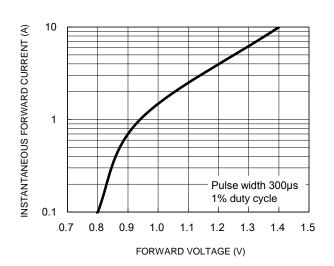
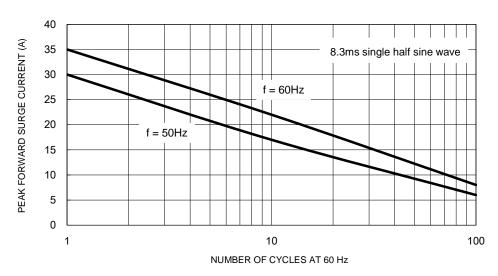


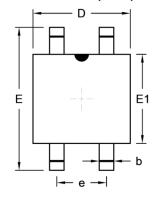
Fig.5 Maximum Non-Repetitive Forward Surge Current

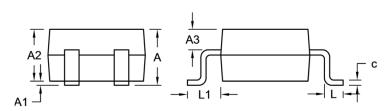




## **PACKAGE OUTLINE DIMENSIONS**

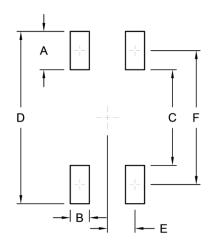
## **TO-269AA (MBS)**





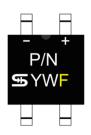
| DIM.   | Unit (mm) |      | Unit (inch) |       |
|--------|-----------|------|-------------|-------|
| DIIVI. | Min.      | Max. | Min.        | Max.  |
| Α      | -         | 2.90 | -           | 0.114 |
| A1     | -         | 0.20 | -           | 0.008 |
| A2     | 2.30      | 2.70 | 0.091       | 0.106 |
| A3     | 0.95      | 1.53 | 0.037       | 0.060 |
| b      | 0.56      | 0.84 | 0.022       | 0.033 |
| С      | 0.15      | 0.35 | 0.006       | 0.014 |
| D      | 4.50      | 4.90 | 0.177       | 0.193 |
| E      | -         | 6.90 | -           | 0.272 |
| E1     | 3.60      | 5.00 | 0.142       | 0.197 |
| е      | 2.20      | 2.60 | 0.087       | 0.102 |
| L      | 0.70      | 1.10 | 0.028       | 0.043 |
| L1     | 1.10      | 2.12 | 0.043       | 0.083 |

## **SUGGESTED PAD LAYOUT**



| Symbol | Unit (mm) | Unit (inch) |
|--------|-----------|-------------|
| Α      | 1.80      | 0.071       |
| В      | 0.90      | 0.035       |
| С      | 4.50      | 0.177       |
| D      | 8.10      | 0.319       |
| E      | 1.30      | 0.051       |
| F      | 6.30      | 0.248       |

## **MARKING DIAGRAM**



P/N = Marking Code YW = Date Code F = Factory Code



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